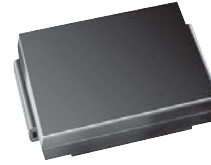


Surface Mount Glass Passivated Rectifier

Major Ratings and Characteristics

$I_{F(AV)}$	3.0 A
V_{RRM}	50 V to 1000 V
I_{FSM}	100 A
I_R	10 μ A
V_F	1.15 V
T_j max.	150 °C



DO-214AB (SMC)

Features

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Meets MSL level 1, per J-STD-020C
- Solder Dip 260 °C, 40 seconds



Mechanical Data

Case: DO-214AB (SMC)

Epoxy meets UL-94V-0 Flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

Polarity: Color band denotes cathode end

Typical Applications

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes for consumer, automotive and Telecommunication

Maximum Ratings

($T_A = 25$ °C unless otherwise noted)

Parameter	Symbol	S3A	S3B	S3D	S3G	S3J	S3K	S3M	Unit
Device marking code		SA	SB	SD	SG	SJ	SK	SM	
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_L = 103$ °C ⁽¹⁾	$I_{F(AV)}$	3.0							A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	100							A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150							°C

Electrical Characteristics

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

Parameter	Test condition	Symbol	S3A	S3B	S3D	S3G	S3J	S3K	S3M	Unit
Maximum instantaneous forward voltage	at 2.5 A	V_F	1.15							V
Maximum DC reverse current at rated DC blocking voltage	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 125\text{ }^\circ\text{C}$	I_R	10 250							μA
Typical reverse recovery time	at $I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{rr} = 0.25\text{ A}$	t_{rr}	2.5							μs
Typical junction capacitance	at 4.0 V, 1 MHz	C_J	60							pF

Thermal Characteristics

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	S3A	S3B	S3D	S3G	S3J	S3K	S3M	Unit
Typical thermal resistance ⁽¹⁾	$R_{\theta JA}$ $R_{\theta JL}$	47 13							$^\circ\text{C/W}$

Notes:

(1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0 mm) copper pad area

Ratings and Characteristics Curves

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

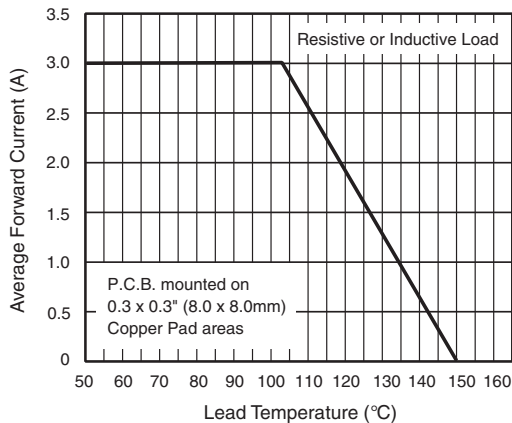


Figure 1. Forward Current Derating Curve

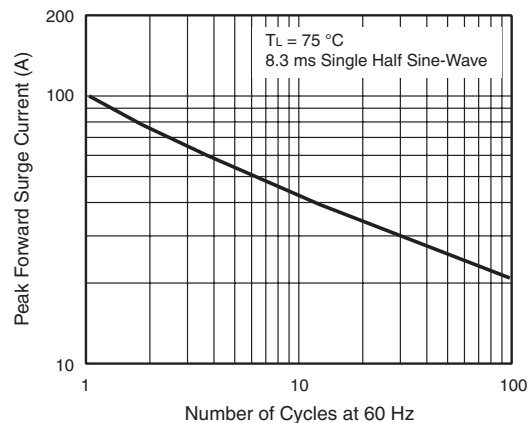


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

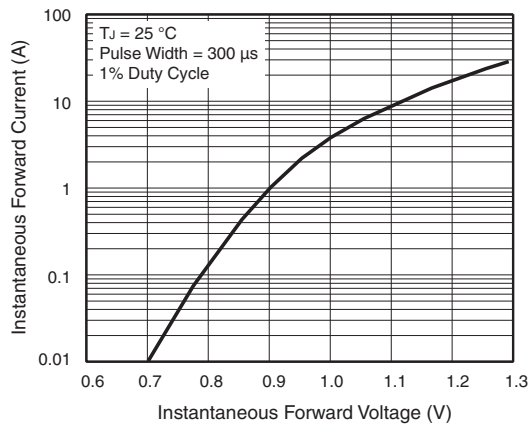


Figure 3. Typical Instantaneous Forward Characteristics

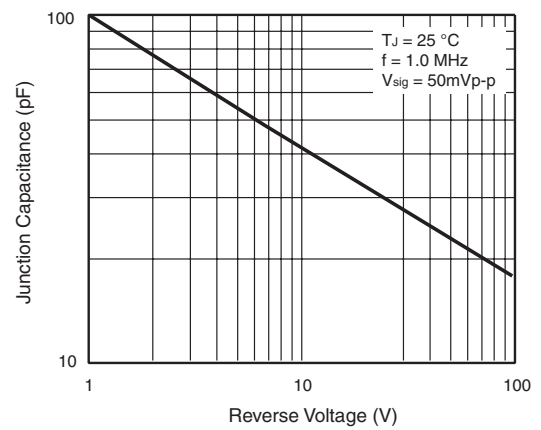


Figure 5. Typical Junction Capacitance

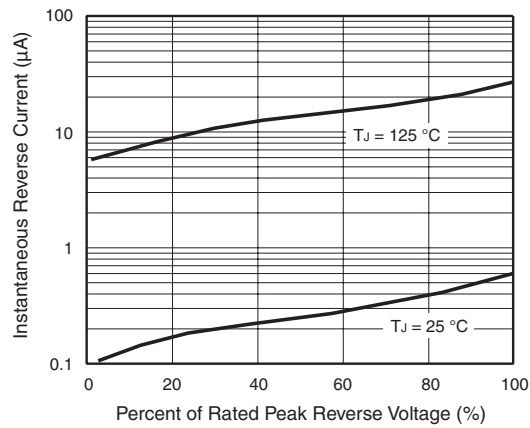


Figure 4. Typical Reverse Characteristics

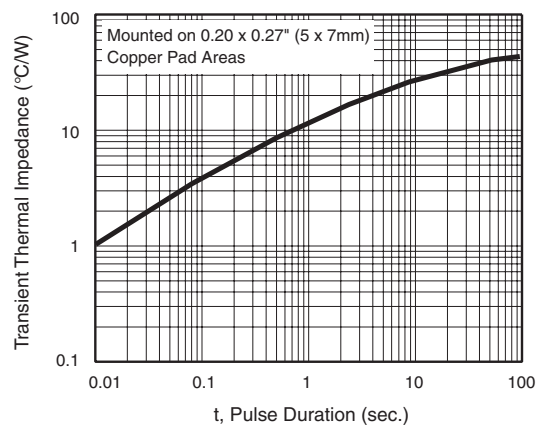


Figure 6. Typical Transient Thermal Impedance

Package outline dimensions in inches (millimeters)

